



SINGLE INVERTER GATE

Description

The 74AHCT1G04Q is an automotive compliant single, two-input positive NAND gate with a standard push-pull output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

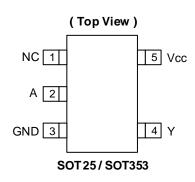
$$Y = \overline{A}$$

Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 4.5V to 5.5V
- ±8mA Output Drive at 5.0V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHCT1G04Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Pin Assignments



Applications

- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

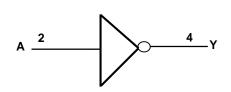
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Description
NC	No Connection
А	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Input	Output
Α	Y
Н	L
L	Н

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to V _{CC} + 0.5	V
Ік	Input Clamp Current VI < 0	-20	mA
Іок	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
lo	Continuous Output Current (V _O = 0 to V _{CC})	±25	mA
lcc	Continuous Current Through Vcc	50	mA
Ignd	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C
PD Total Power Dissipation (Note 6)		250	mW

Notes: 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

Symbol	Pa	rameter	Min	Max	Unit
Vcc	Operating Voltage	—	4.5	5.5	V
VIH	High-Level Input Voltage	$V_{CC} = 5V \pm 0.5V$	2.0	_	V
VIL	Low-Level Input Voltage $V_{CC} = 5V \pm 0.5V$		_	0.8	V
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Іон	High-Level Output Current	$V_{CC} = 5V \pm 0.5V$	—	-8	mA
Iol	Low-Level Output Current	$V_{CC} = 5V \pm 0.5V$	_	8	mA
Δt/ΔV	Input Transition Rise or Fall Rate $V_{CC} = 5V \pm 0.5V$		—	20	ns/V
TA	Ambient Temperature —		-40	+125	°C

Note: 7. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (All typical values are at Vcc 5V, TA = +25°C.)

		T (0)			+25°C		-40°C te	o +85°C	-40°C to	+125°C	
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit
Maria	High Level	$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$	4.5V	4.4	4.5		4.4	_	4.4		V
V _{OH}	Output Voltage	$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -8mA$	4.5V	3.94			3.8	_	3.70		V
	V _{OL} Low Level Output Voltage	V _I = V _{IH} or V _{IL} I _{OL} = 50µA	4.5V	_	0	0.1		0.1		0.1	V
VOL		$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	V
h	Input Current	VI = 5.5V or GND	0 to 5.5V	_	_	±0.1	_	±1	—	±2	μA
Δlcc	Additional Supply Current	$V_{I} = 3.4V;$ $I_{O} = 0$	5.5V	_		1.35		1.5	_	1.5	mA
Icc	Supply Current	$V_1 = 5.5V \text{ or GND}$ $I_0 = 0$	5.5V	_	_	1	_	10	_	40	μΑ
Cı	Input Capacitance	VI = VCC or GND	5.5V	_	1.5	10		10		10	pF



Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Мах	Unit
0	Thermal Resistance	SOT25			184	_	0000
θја	Junction-to-Ambient	SOT353	Note 8	—	385	—	°C/W
0	Thermal Resistance	SOT25		_	62	_	
θις	Junction-to-Case	SOT353	Note 8	_	164	—	°C/W

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Vcc = 5V ± 0.5V (See Figure 1, Typical values at Vcc = 5V.)

Demonster	From	То	Test	+25°C		-40°C to +85°C		-40°C to +125°C		l la it	
Parameter	Parameter (Input) (Output)	Conditions	Min	Тур	Мах	Min	Max	Min	Max	Unit	
		D V	CL = 15pF	1.0	3.4	6.7	1.0	7.5	1.0	8.5	ns
tpD	A or B	Y	$C_L = 50 pF$	1.0	4.9	7.7	1.0	8.5	1.0	10.0	ns

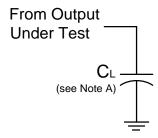
Operating Characteristics

 $T_A = +25^{\circ}C$

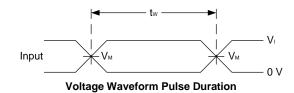
Parameter		Test Conditions	V _{CC} = 5V Typ	Unit
Cpd	Power Dissipation Capacitance	f = 1MHz No Load	10	pF

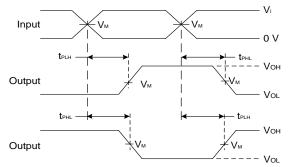


Measurement Information



Vcc		Inputs		Output	CL
VCC	Vi	tr/tr	Vм	νм	UL
5V±0.5V	GND to Vcc	≤3ns	1.5V	Vcc/2	15pF
5V±0.5V	GND to Vcc	≤3ns	1.5V	Vcc/2	50pF





Voltage Waveform Propagation Delay Times Inverting and Non-Inverting Outputs

Figure 1. Load Circuit and Voltage Waveforms

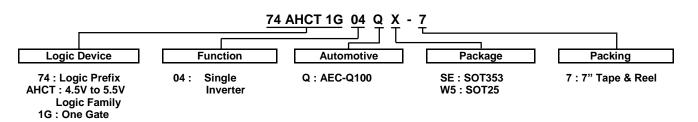
Notes:

- A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate \leq 1MHz.
- C. Inputs are measured separately one transition per measurement.

D. t_{PLH} and t_{PHL} are the same as t_{PD} .



Ordering Information (Note 9)

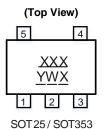


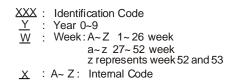
Part Number	Part Number Package Package		Package Size	7" Tape and Reel		
Fait Number	Code	(Notes 10 & 11)	Fackage Size	Quantity	Part Number Suffix	
74AHCT1G04QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7	
74AHCT1G04QW5-7	W5	SOT25	3.0mm × 2.8mm × 1.2mm 0.95mm lead pitch	3000/Tape & Reel	-7	

Notes:

9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information





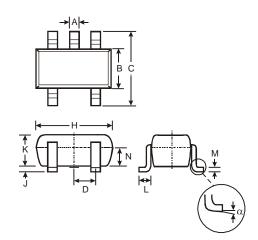
Part Number	Package	Identification Code	
74AHCT1G04QW5-7	SOT25	ZTQ	
74AHCT1G04QSE-7	SOT353	ZTQ	



Package Outline Dimensions

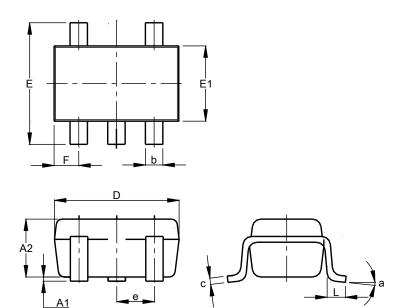
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



	SO	[25]							
Dim	Dim Min Max Typ								
Α	0.35	0.50	0.38						
В	1.50	1.70	1.60						
С	2.70	3.00	2.80						
D	-	-	0.95						
Н	2.90	3.10	3.00						
J	0.013	0.10	0.05						
κ	1.00	1.30	1.10						
L	0.35	0.55	0.40						
М	0.10	0.20	0.15						
Ν	0.70	0.80	0.75						
α	0°	8°	-						
All D	imensi	ons in	mm						

(2) Package Type: SOT353



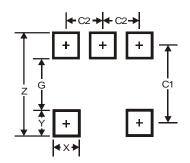
SOT353				
Dim	Min	Max	Тур	
A1	0.00	0.10	0.05	
A2	0.90	1.00	0.95	
b	0.10	0.30	0.25	
С	0.10	0.22	0.11	
D	1.80	2.20	2.15	
E	2.00	2.20	2.10	
E1	1.15	1.35	1.30	
е	0.650 BSC			
F	0.40	0.45	0.425	
L	0.25	0.40	0.30	
а	0°	8°		
All Dimensions in mm				



Suggested Pad Layout

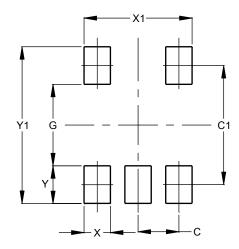
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Y	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0064 grams (Approximate)



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